

NPN SILICON PLANAR MEDIUM POWER TRANSISTORS IN SOT223
Features

- $I_C = 1A$ Continuous Collector Current
- Low Saturation Voltage $V_{CE(sat)} < 500mV$ @ 0.5A
- Gain groups 10 and 16
- Epitaxial Planar Die Construction
- Complementary PNP types: BCP51, 52 and 53
- **Lead-Free, RoHS Compliant (Note 1)**
- **Halogen and Antimony Free. "Green" Devices (Note 2)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound (Note 2)
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish
- Weight: 0.112 grams (Approximate)

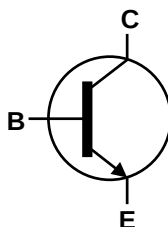
Applications

- Medium Power Switching or Amplification Applications
- AF driver and output stages

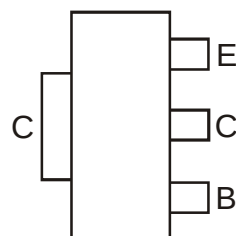
SOT223



Top View



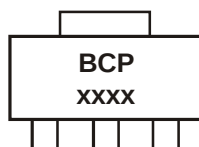
Device Symbol


 Top View
Pin-Out

Ordering Information (Note 3)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
BCP54TA	BCP 54	7	12	1,000
BCP5410TA	BCP 5410	7	12	1,000
BCP5416TA	BCP 5416	7	12	1,000
BCP55TA	BCP 55	7	12	1,000
BCP5510TA	BCP 5510	7	12	1,000
BCP5516TA	BCP 5516	7	12	1,000
BCP56TA	BCP 56	7	12	1,000
BCP5610TA	BCP 5610	7	12	1,000
BCP5616TA	BCP 5616	7	12	1,000
BCP5616TC	BCP 5616	13	12	4,000

- Notes:
1. No purposefully added lead.
 2. Diodes Inc's "Green" Policy can be found on our website at <http://www.diodes.com>
 3. For packaging details, go to our website <http://www.diodes.com>

Marking Information


BCP = Product Type Marking Code, Line 1.
 XXXX = Product Type Marking Code, Line 2 as follows:

BCP54 = 54
 BCP5410 = 5410
 BCP5416 = 5416

BCP55 = 55
 BCP5510 = 5510
 BCP5516 = 5516

BCP56 = 56
 BCP5610 = 5610
 BCP5616 = 5616

Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

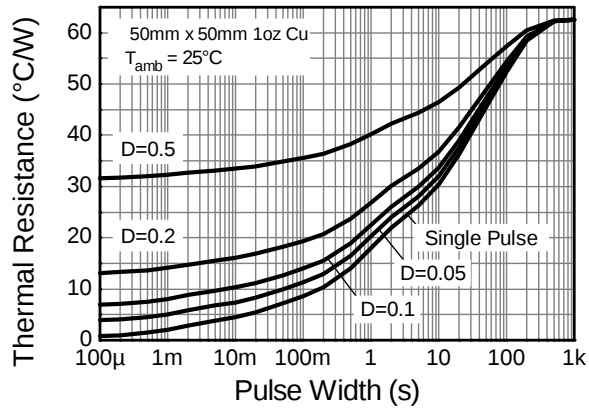
Characteristic	Symbol	BCP54	BCP55	BCP56	Unit
Collector-Base Voltage	V _{CBO}	45	60	100	V
Collector-Emitter Voltage	V _{CEO}	45	60	80	V
Emitter-Base Voltage	V _{EBO}	5			V
Continuous Collector Current	I _C	1			A
Peak Pulse Collector Current	I _{CM}	2			
Continuous Base Current	I _B	100			mA
Peak Pulse Base Current	I _{BM}	200			

Thermal Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

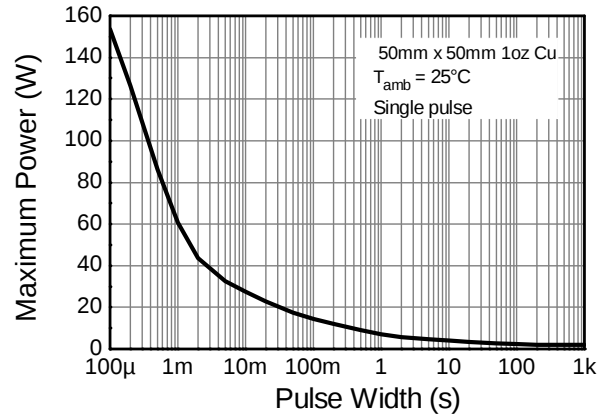
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 4)	P_D	2	W
Thermal Resistance, Junction to Ambient (Note 4)	$R_{\theta JA}$	62	$^\circ\text{C/W}$
Thermal Resistance, Junction to Leads (Note 5)	$R_{\theta JL}$	19.4	$^\circ\text{C/W}$
Operating and Storage Temperature Range	T_J, T_{STG}	-65 to +150	$^\circ\text{C}$

- Notes:
4. For a device surface mounted on 50mm X 50mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
 5. Thermal resistance from junction to solder-point (at the end of the collector lead).

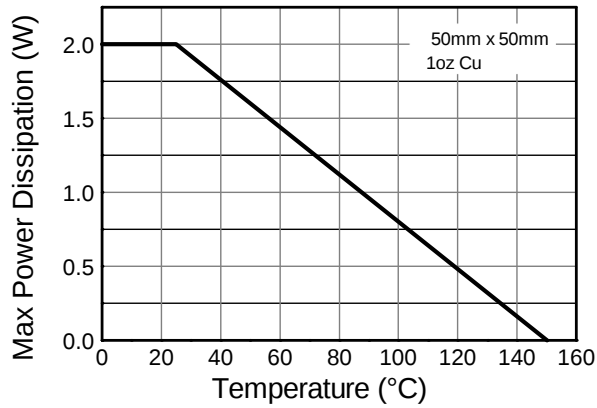
Thermal Characteristics



Transient Thermal Impedance



Pulse Power Dissipation



Derating Curve

Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BCP54	BV_{CBO}	45	-	-	V	$I_C = 100\mu\text{A}$
	BCP55		60				
	BCP56		100				
Collector-Emitter Breakdown Voltage (Note 6)	BCP54	BV_{CEO}	45	-	-	V	$I_C = 10\text{mA}$
	BCP55		60				
	BCP56		80				
Emitter-Base Breakdown Voltage		BV_{EBO}	5	-	-	V	$I_E = 10\mu\text{A}$
Collector Cut-off Current		I_{CBO}	-	-	0.1 20	μA	$V_{CB} = 30\text{V}$ $V_{CB} = 30\text{V}, T_A = 150^\circ\text{C}$
Emitter Cut-off Current		I_{EBO}	-	-	20	nA	$V_{EB} = 4\text{V}$
Static Forward Current Transfer Ratio (Note 6)	All versions	h_{FE}	25	-	-		$I_C = 5\text{mA}, V_{CE} = 2\text{V}$
			40	-	250		$I_C = 150\text{mA}, V_{CE} = 2\text{V}$
			25	-	-		$I_C = 500\text{mA}, V_{CE} = 2\text{V}$
	10 gain grp		63	-	160		$I_C = 150\text{mA}, V_{CE} = 2\text{V}$
	16 gain grp		100	-	250		$I_C = 150\text{mA}, V_{CE} = 2\text{V}$
Collector-Emitter Saturation Voltage (Note 6)		$V_{CE(sat)}$	-	-	0.5	V	$I_C = 500\text{mA}, I_B = 50\text{mA}$
Base-Emitter Turn-On Voltage (Note 6)		$V_{BE(on)}$	-	-	1.0	V	$I_C = 500\text{mA}, V_{CE} = 2\text{V}$
Transition Frequency		f_T	150	-	-	MHz	$I_C = 50\text{mA}, V_{CE} = 10\text{V}$ $f = 100\text{MHz}$
Output Capacitance		C_{obo}	-	-	25	pF	$V_{CB} = 10\text{V}, f = 1\text{MHz}$

Notes: 6. Measured under pulsed conditions. Pulse width $\leq 300\mu\text{s}$. Duty cycle $\leq 2\%$.

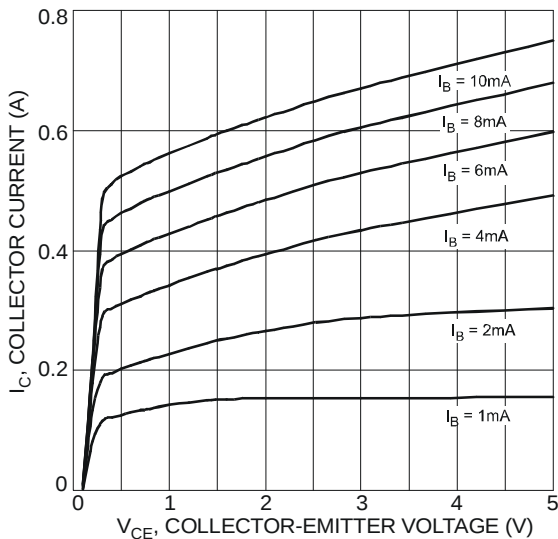


Fig. 1 Typical Collector Current vs. Collector-Emitter Voltage

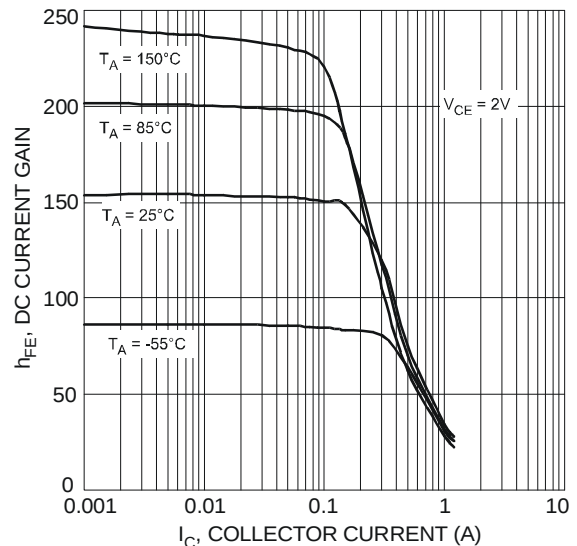


Fig. 2 Typical DC Current Gain vs. Collector Current

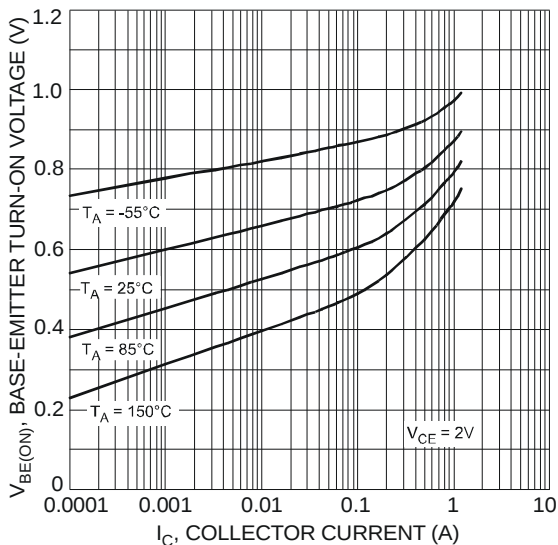


Fig. 3 Typical Base-Emitter Turn-On Voltage vs. Collector Current

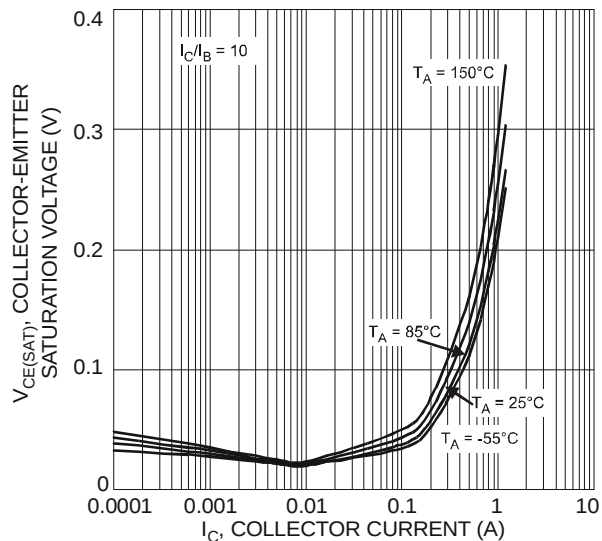


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

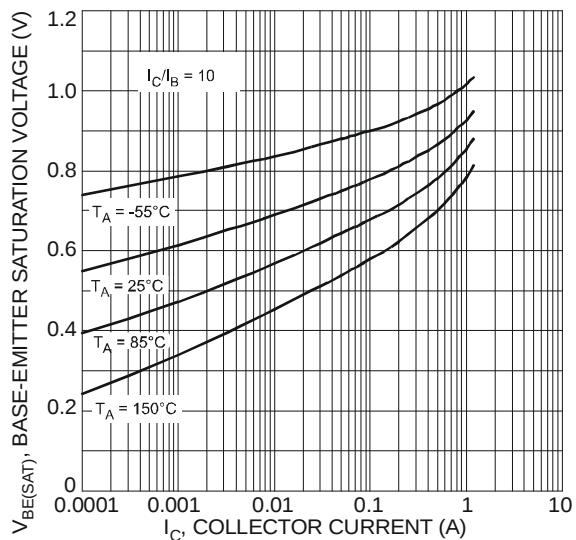


Fig. 5 Typical Base-Emitter Saturation Voltage vs. Collector Current

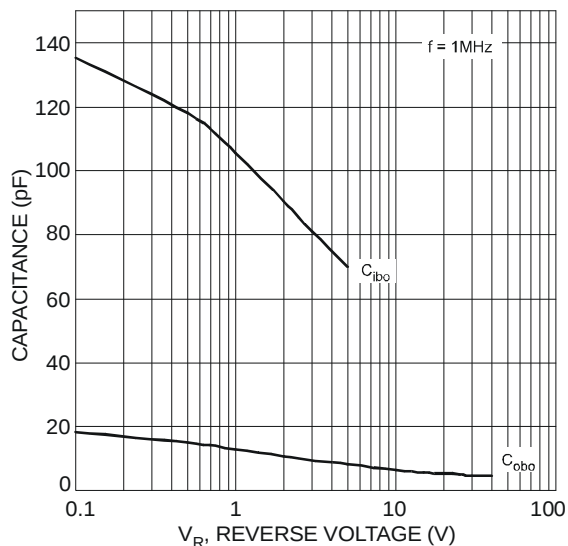


Fig. 6 Typical Capacitance Characteristics

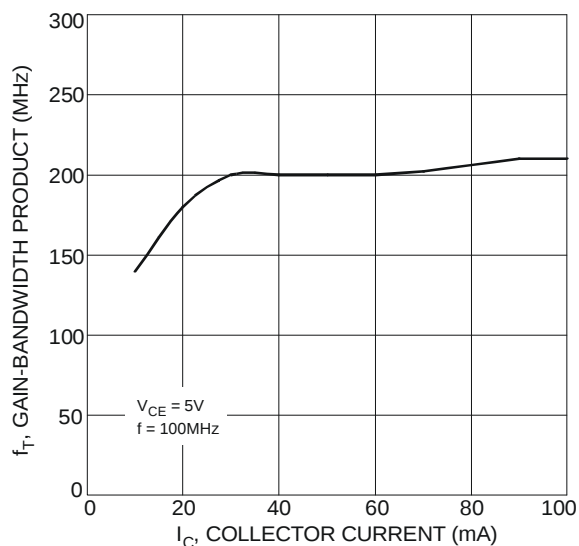
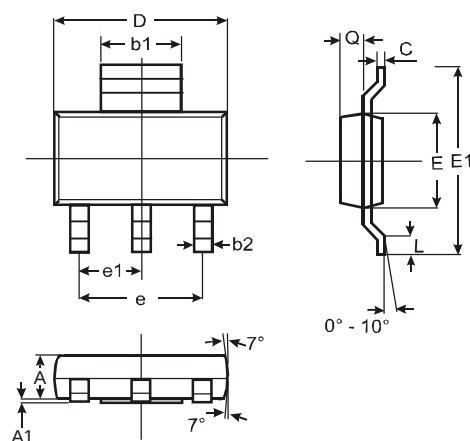


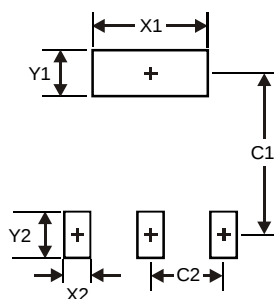
Fig. 7 Typical Gain-Bandwidth Product vs. Collector Current

Package Outline Dimensions



SOT223			
Dim	Min	Max	Typ
A	1.55	1.65	1.60
A1	0.010	0.15	0.05
b1	2.90	3.10	3.00
b2	0.60	0.80	0.70
C	0.20	0.30	0.25
D	6.45	6.55	6.50
E	3.45	3.55	3.50
E1	6.90	7.10	7.00
e	—	—	4.60
e1	—	—	2.30
L	0.85	1.05	0.95
Q	0.84	0.94	0.89
All Dimensions in mm			

Suggested Pad Layout



Dimensions	Value (in mm)
X1	3.3
X2	1.2
Y1	1.6
Y2	1.6
C1	6.4
C2	2.3

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